

SHENZHEN NANSHENGDA ELECTRONICS CO.,LTD Wide Input Voltage Three Terminal Positive Voltage Regulator

# NSD78XX Series Three Terminal Voltage Regulator

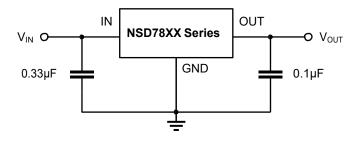
### 1 Introduction

The NSD78XX series is a group of three terminal positive voltage linear regulators with multiple fixed output voltages. Under the condition of good heat dissipation, it can provide output current up to 1.5A, and has the functions of internal current limit, short circuit protection, thermal shutdown protection and output transistor SOA protection, which make it relatively difficult to damage. Although designed as fixed voltage regulators without external components, these devices can be used with external components to obtain adjustable voltage and current. Therefore, the NSD78XX series is widely used as fixed voltage regulators, including local (on card) regulators, to eliminate noise and power distribution problems associated with single point regulation.

## 2 Available Packages

PART NUMBER	PACKAGE
	TO-220-3L
NSD78XX Series	TO-220F
NSD76AA Selles	TO-263-2L

**Note:** For all available packages, please refer to the part *Orderable Information.* 





### 3 Features

- Available Fixed Output Voltage: NSD7805:5.0V NSD7806:6.0V NSD7808:8.0V NSD7809:9.0V NSD7810:10.0V NSD7812:12.0V NSD7815:15.0V NSD7815:15.0V NSD7818:18.0V NSD7824:24.0V
- Output Current up to 1.5A
- Output Voltage Tolerance at T<sub>J</sub> = 25°C: ±2% for Conventional Device ±1% can be Customized
- Operating Junction Temperature: -40 ~ 125°C
- Output Voltage Tolerances of ±4% over the Temperature Range
- Dropout Voltage: 2V@1A
- Power Supply Rejection Ratio: 70dB@120Hz (V<sub>OUT</sub> = 5.0V)
- Output Transistor SOA Protection
- Internal Current Limit
- Short Circuit Protection
- Thermal Shutdown Protection

## 4 Applications

- AC Inventors
- DC Motor Drivers
- Household Electric Appliances
- HVAC Systems
- Industrial Power Supplies
- SMPS Post Regulation
- Solar Energy String Inventors
- Test and Measurement Equipment

## 5 Orderable Information

MODEL	DEVICE	PACKAGE	OP TJ	ECO PLAN	MSL	PACKING OPTION	SORT
	Conventional Device						
NSD7805	NSD7805	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7806	NSD7806	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7808	NSD7808	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7809	NSD7809	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7812	NSD7812	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7815	NSD7815	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7818	NSD7818	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7824	NSD7824	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7805	NSD7805	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7806	NSD7806	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7808	NSD7808	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7809	NSD7809	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7812	NSD7812	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7815	NSD7815	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7818	NSD7818	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active
NSD7824	NSD7824	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Active

### 5 Orderable Information

MODEL	DEVICE	PACKAGE	OP TJ	ECO PLAN	MSL	PACKING OPTION	SORT
		Cor	ventional Devi	ce (continued)	•		
NSD7805	NSD7805	TO-263-2L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tape and Reel 800 Units / Reel	Active
NSD7806	NSD7806	TO-263-2L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tape and Reel 800 Units / Reel	Active
NSD7808	NSD7808	TO-263-2L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tape and Reel 800 Units / Reel	Active
NSD7809	NSD7809	TO-263-2L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tape and Reel 800 Units / Reel	Active
NSD7812	NSD7812	TO-263-2L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tape and Reel 800 Units / Reel	Active
NSD7815	NSD7815	TO-263-2L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tape and Reel 800 Units / Reel	Active
NSD7818	NSD7818	TO-263-2L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tape and Reel 800 Units / Reel	Active
NSD7824	NSD7824	TO-263-2L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tape and Reel 800 Units / Reel	Active
			Customized	Device			
	NSD78XX	TO-220-3L	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Customized
NSD78XX ±1% grade	NSD78XX	TO-220F	-40 ~ 125°C	RoHS & Green	Level 3 168 HR	Tube 50 Units / Rail	Customized
	NSD78XX	TO-263-2L	-40 ~ 125°C	-40 ~ 125°C RoHS & Green Level 3 168 HR		Tape and Reel 800 Units / Reel	Customized
Others	-	-	-	-	-	-	Customized

Note:

**ECO PLAN**: For the RoHS and Green certification standards of this product, please refer to the official report provided by NSD

**MSL**: Moisture Sensitivity Level. Determined according to NSD industry standard classification.

SORT: Specifically defined as follows:

Active: Recommended for new products;

Customized: Products manufactured to meet the specific needs of customers;

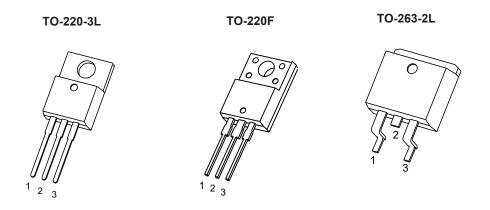
Preview: The device has been released and has not been fully mass produced. The sample may or may not be available;

NoRD: It is not recommended to use the device for new design. The device is only produced for the needs of existing customers;

Obsolete: The device has been discontinued.

# 6 Pin Configuration and Marking Information

## 6.1 Pin Configuration



### Figure 6-1. Pin Configuration

	P	in Configura		
PIN NAME	TO-220-3L	TO-220F	TO-263-2L	DESCRIPTION
IN	1	1	1	Input of the device.
GND	2	2	2	Regulator ground.
OUT	3	3	3	Output of the device.

#### 7.1 Absolute Maximum Ratings

(over operating free-air temperature range, ι	unless otherwise specified)
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CHARACTERISTIC			SYMBOL	VALUE	UNIT
5.0		5.0 – 18 V		35	V
Maximum input volta	Maximum input voltage range <sup>(2)</sup>		- Vin max	40	V
Maxi	Maximum output current			1.5	А
		TO-220-3L			
Maximum power dissipation	NSD78XX Series	TO-220F	Рр мах	Internally Limited <sup>(3)</sup>	W
dissipation		TO-263-2L			
Maximu	m junction tem	perature	Тј Мах	150	°C
Storage temperature			T <sub>stg</sub>	-65 ~ 150	°C
Soldering temperature & time			T <sub>solder</sub>	260°C, 10s	-

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to network ground terminal.

(3) Refer to Thermal Information for details.

### 7.2 Recommend Operating Conditions

PARAMETER		SYMBOL	MIN.	NOM.	MAX.	UNIT
	NSD7805		-	-	32	
	NSD7806		-	-	32	
	NSD7808		-	-	32	
Input voltage range	NSD7809		-	-	32	V
	NSD7810	V <sub>IN</sub>	-	-	32	V
	NSD7812		-	-	32	
	NSD7815		-	-	32	
	NSD7818		-	-	32	
	NSD7824		-	-	37	
Operating juncti	Operating junction temperature		-40	-	125	°C
Operating ambie	ent temperature	TA	-	_(4)	-	°C

(4) It is necessary to ensure that the operating junction temperature of the device does not exceed the rated value of the recommended operating conditions when using the device for design.

### 7.3 ESD Ratings

ESD RATING	SYMBOL	VALUE	UNIT	
Electrostatic discharge <sup>(5)</sup>	Human body model	Vesd-hbm	6000	V

(5) ESD testing is conducted in accordance with the relevant specifications formulated by the Joint Electronic Equipment Engineering Commission (NSD). The human body model (HBM) electrostatic discharge test is based on the JESD22-114D test standard, using a 100pF capacitor and discharging to each pin of the device through a resistance of  $1.5k\Omega$ . The electrostatic discharge test in mechanical model (MM) is based on the JESD22-115-A test standard and uses a 200pF capacitor to discharge directly to each pin of the device.

### 7.4 Thermal Information

THERMAL METRIC <sup>(6)</sup>	SYMBOL	SYMBOL NSD78XX Series			UNIT
	_	TO-220-3L	TO-220F	TO-263-2L	°C/M
Junction-to-ambient thermal resistance	Roja	65.1	66.4	62.3	°C/W
Junction-to-case thermal resistance	R <sub>ojc</sub>	TO-220-3L	TO-220F	TO-263-2L	°C/W
Junction-to-case mermai resistance	OlC	5.4	6.2	5.3	C/ W
Reference maximum power dissipation for	P <sub>D Ref</sub>	TO-220-3L	TO-220F	TO-263-2L	\\\/
continuous operation	. D Kei	1.53	1.51	1.60	W

(6)  $T_A = 25^{\circ}$ C, all numbers are typical, and apply for packages soldered directly onto a PCB board in still air without extra heat dissipation pads.

#### 7.5 Electrical Characteristics

7805 (V<sub>IN</sub> = 10V, I<sub>OUT</sub> = 500mA, C<sub>IN</sub> =  $0.33\mu$ F, C<sub>OUT</sub> =  $0.1\mu$ F, T<sub>J</sub> = 25°C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT
		±2% grade <sup>(8)</sup>	4.90	E 00	5.10	
Output voltage	Vout	±1% grade <sup>(8)</sup>	4.95	5.00	5.05	
Output voltage	VOUT	$I_{OUT} = 5$ mA to 1A, $V_{IN} = 7.5$ to 20V, T <sub>J</sub> = -40 to 125°C	4.80	5.00	5.20	V
Line regulation		V <sub>IN</sub> = 7.5 to 20V, I <sub>OUT</sub> = 500mA	-	25	50	mV
Load regulation	$\Delta V_{RLOAD}$	I <sub>OUT</sub> = 5mA to 1.5A	-	20	75	mV
Quiescent current	lα	Iout = 0mA	-	5	8	mA
Quiescent current	Δlq	Iout = 5mA to 1A	-	0.1	0.8	
change		V <sub>IN</sub> = 8 to 25V, I <sub>OUT</sub> = 500mA	-	0.3	0.8	mA
Output voltage	ΔVουτ / ΔΤ		-	0.4	-	mV/°C
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)	-	-	80	-	ppm/°C
Output noise voltage	V <sub>N</sub>	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / V <sub>O</sub>
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 8 to 18V, I <sub>OUT</sub> = 500mA	-	70	-	dB
Dropout voltage <sup>(9)</sup>	VD	I <sub>OUT</sub> = 1A	-	2.0	-	V
Output resistance	Rout	f = 1kHz	-	10	-	mΩ
Short circuit current	I <sub>SC</sub>	V <sub>IN</sub> = 35V		10	-	mA
Peak current	I <sub>PK</sub>	V <sub>IN</sub> = 10V	-	2.5	-	А

#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8)  $\pm 2\%$  for conventional device,  $\pm 1\%$  can be customized.

### 7.5 Electrical Characteristics (continued)

7806 ( $V_{IN} = 11V$ ,  $I_{OUT} = 500$ mA,  $C_{IN} = 0.33\mu$ F,  $C_{OUT} = 0.1\mu$ F,  $T_J = 25$ °C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT
		±2% grade <sup>(8)</sup>	5.88	6.00	6.12	
Output voltage	Vout	±1% grade <sup>(8)</sup>	5.94	0.00	6.06	v
	VOUT	$I_{OUT} = 5mA \text{ to } 1A, V_{IN} = 8.6 \text{ to } 21V,$ $T_J = -40 \text{ to } 125^{\circ}C$	5.76	6.00	6.24	V
Line regulation	$\Delta V_{RLINE}$	V <sub>IN</sub> = 8.6 to 21V, I <sub>OUT</sub> = 500mA	-	-	60	mV
Load regulation	$\Delta V_{RLOAD}$	I <sub>OUT</sub> = 5mA to 1.5A	-	-	90	mV
Quiescent current	Ι <sub>Q</sub>	I <sub>OUT</sub> = 0mA	-	5.0	8.0	mA
Quiescent current	Δlq	Iout = 5mA to 1A	-	0.1	0.8	m (
change		V <sub>IN</sub> = 8.6 to 21V, I <sub>OUT</sub> = 500mA	-	0.3	0.8	mA
Output voltage	ΔVουτ / ΔΤ		-	0.48	-	mV/°C
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)	-	-	80	-	ppm/°C
Output noise voltage	VN	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / Vo
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 9.5 to 19.5V, I <sub>OUT</sub> = 500mA	-	65	-	dB
Dropout voltage <sup>(9)</sup>	VD	louτ = 1A	-	2.0	-	V
Output resistance	Rout	f = 1kHz	-	10	-	mΩ
Short circuit current	lsc	V <sub>IN</sub> = 35V		200	-	mA
Peak current	Ірк	V <sub>IN</sub> = 11V	-	2.5	-	А

#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8)  $\pm 2\%$  for conventional device,  $\pm 1\%$  can be customized.

### 7.5 Electrical Characteristics (continued)

7808 ( $V_{IN} = 14V$ ,  $I_{OUT} = 500$ mA,  $C_{IN} = 0.33\mu$ F,  $C_{OUT} = 0.1\mu$ F,  $T_J = 25$ °C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT
		±2% grade <sup>(8)</sup>	7.84	8.00	8.16	
Output valte re	Maria	±1% grade <sup>(8)</sup>	7.92	0.00	8.08	
Output voltage	Vout	$I_{OUT} = 5$ mA to 1A, $V_{IN} = 10.6$ V to 23V, $T_J = -40$ to 125°C	7.68	8.00	8.32	
Line regulation	$\Delta V_{RLINE}$	V <sub>IN</sub> = 10.6 to 23V, I <sub>OUT</sub> = 500mA	-	-	80	mV
Load regulation	$\Delta V_{RLOAD}$	Iout = 5mA to 1.5A	-	-	120	mV
Quiescent current	lq	Iout = 0mA	-	5.0	8.0	mA
Quiescent current	Δlq	I <sub>OUT</sub> = 5mA to 1A	-	0.1	0.8	
change		V <sub>IN</sub> = 10.6 to 23V, I <sub>OUT</sub> = 500mA	-	0.3	0.8	mA
Output voltage	ΔV <sub>OUT</sub> / ΔT		-	0.64	-	mV/°C
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)		-	80	-	ppm/°C
Output noise voltage	V <sub>N</sub>	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / Vo
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 11.5 to 21.5V, Іоит = 500mA	-	65	-	dB
Dropout voltage <sup>(9)</sup>	VD	Iout = 1A	-	2.0	-	V
Output resistance	Rout	f = 1kHz	-	10	-	mΩ
Short circuit current	Isc	V <sub>IN</sub> = 35V		200	-	mA
Peak current	Ірк	V <sub>IN</sub> = 14V	-	2.5	-	Α

#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8) ±2% for conventional device, ±1% can be customized.

### 7.5 Electrical Characteristics (continued)

7809 ( $V_{IN}$  = 15V,  $I_{OUT}$  = 500mA,  $C_{IN}$  = 0.33 $\mu$ F,  $C_{OUT}$  = 0.1 $\mu$ F,  $T_J$  = 25°C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT	
		±2% grade <sup>(8)</sup>	8.82	9.00	9.18		
Output voltage	Vout	±1% grade <sup>(8)</sup>	8.91	9.00	9.09	v	
Output voitage	VOUT	I <sub>OUT</sub> = 5mA to 1A, V <sub>IN</sub> = 11.5 to 23V, T <sub>J</sub> = -40 to 125°C	8.64	9.00	9.36	V	
Line regulation		V <sub>IN</sub> = 11.5 to 23V, I <sub>OUT</sub> = 500mA	-	-	90	mV	
Load regulation	$\Delta V_{RLOAD}$	I <sub>OUT</sub> = 5mA to 1.5A	-	-	135	mV	
Quiescent current	Ι <sub>Q</sub>	I <sub>OUT</sub> = 0mA	-	5.0	8.0	mA	
Quiescent current		Iout = 5mA to 1.5A	-	0.1	0.8	mA	
change	Δlq	V <sub>IN</sub> = 11.5 to 23V, I <sub>OUT</sub> = 500mA	-	0.3	0.8		
Output voltage	ΔVουτ / ΔΤ		-	0.72	-	mV/°C	
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)	-	-	80	-	ppm/°C	
Output noise voltage	V <sub>N</sub>	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / Vo	
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 11.5 to 21.5V, Ιουτ = 500mA	-	65	-	dB	
Dropout voltage <sup>(9)</sup>	VD	Iout = 1A	-	2.0	-	V	
Output resistance	Rout	f = 1kHz	-	10	-	mΩ	
Short circuit current	lsc	V <sub>IN</sub> = 35V		200	-	mA	
Peak current	Ірк	V <sub>IN</sub> = 15V	-	2.5	-	А	

#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8)  $\pm 2\%$  for conventional device,  $\pm 1\%$  can be customized.

### 7.5 Electrical Characteristics (continued)

7810 ( $V_{IN}$  = 15V,  $I_{OUT}$  = 500mA,  $C_{IN}$  = 0.33 $\mu$ F,  $C_{OUT}$  = 0.1 $\mu$ F,  $T_J$  = 25°C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT
		±2% grade <sup>(8)</sup>	9.8	10.0	10.2	
Output valte re		±1% grade <sup>(8)</sup>	9.9	10.0	10.1	
Output voltage	Vout	$I_{OUT} = 5$ mA to 1A, $V_{IN} = 12.5$ to 23V, $T_J = -40$ to 125°C	9.6	10.0	10.4	
Line regulation	$\Delta V_{RLINE}$	V <sub>IN</sub> = 12.5 to 23V, I <sub>OUT</sub> = 500mA	-	-	90	mV
Load regulation	$\Delta V_{RLOAD}$	I <sub>OUT</sub> = 5mA to 1.5A	-	-	135	mV
Quiescent current	Ι <sub>Q</sub>	I <sub>OUT</sub> = 0mA	-	5.0	8.0	mA
Quiescent current		Iout = 5mA to 1.5A	-	0.1	0.8	mA
change	Δlq	V <sub>IN</sub> = 12.5 to 23V, I <sub>OUT</sub> = 500mA	-	0.3	0.8	
Output voltage	ΔV <sub>OUT</sub> / ΔT		-	0.72	-	mV/°C
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)	-	-	80	-	ppm/°C
Output noise voltage	V <sub>N</sub>	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / Vo
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 12.5 to 21.5V, Іоит = 500mA	-	65	-	dB
Dropout voltage <sup>(9)</sup>	VD	I <sub>OUT</sub> = 1A	-	2.0	-	V
Output resistance	Rout	f = 1kHz	-	10	-	mΩ
Short circuit current	lsc	V <sub>IN</sub> = 35V		200	-	mA
Peak current	Ірк	V <sub>IN</sub> = 15V	-	2.5	-	А

#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8)  $\pm 2\%$  for conventional device,  $\pm 1\%$  can be customized.

### 7.5 Electrical Characteristics (continued)

7812 ( $V_{IN}$  = 19V,  $I_{OUT}$  = 500mA,  $C_{IN}$  = 0.33 $\mu$ F,  $C_{OUT}$  = 0.1 $\mu$ F,  $T_J$  = 25°C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT
		±2% grade <sup>(8)</sup>	11.76	12.00	12.24	
Output voltage	Vout	±1% grade <sup>(8)</sup>	11.88	12.00	12.12	v
Oulput voltage	VOUT	$I_{OUT} = 5mA$ to 1A, $V_{IN} = 14.8$ to 27V, $T_J = -40$ to 125°C	11.52	12.00	12.48	V
Line regulation	$\Delta V_{RLINE}$	V <sub>IN</sub> = 14.8 to 27V, I <sub>OUT</sub> = 500mA	-	-	120	mV
Load regulation	$\Delta V_{RLOAD}$	Iout = 5mA to 1.5A	-	-	180	mV
Quiescent current	lα	Iout = 0mA	-	5.0	8.0	mA
Quiescent current	Δlq	I <sub>OUT</sub> = 5mA to 1.5A	-	0.1	0.8	mA
change	ΔIQ	V <sub>IN</sub> = 14.8 to 30V, I <sub>OUT</sub> = 500mA	-	0.3	0.8	
Output voltage	ΔVουτ / ΔΤ		-	0.96	-	mV/°C
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)	-	-	80	-	ppm/°C
Output noise voltage	V <sub>N</sub>	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / Vo
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 15 to 25V, Iout = 500mA	-	65	-	dB
Dropout voltage <sup>(9)</sup>	VD	Iout = 1A	-	2.0	-	V
Output resistance	Rout	f = 1kHz	-	11	-	mΩ
Short circuit current	I <sub>SC</sub>	V <sub>IN</sub> = 35V		200	-	mA
Peak current	Ірк	V <sub>IN</sub> = 18V	-	2.5	-	А

#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8)  $\pm 2\%$  for conventional device,  $\pm 1\%$  can be customized.

### 7.5 Electrical Characteristics (continued)

7815 ( $V_{IN}$  = 23V,  $I_{OUT}$  = 500mA,  $C_{IN}$  = 0.33 $\mu$ F,  $C_{OUT}$  = 0.1 $\mu$ F,  $T_J$  = 25°C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT	
		±2% grade <sup>(8)</sup>	14.70	15.00	15.30		
Output valte se	Ň	±1% grade <sup>(8)</sup>	14.85	15.00	15.15		
Output voltage	Vout	I <sub>OUT</sub> = 5mA to 1A, V <sub>IN</sub> = 17.9 to 30V, TJ = -40 to 125°C	14.40	15.00	15.60	V	
Line regulation	$\Delta V_{RLINE}$	V <sub>IN</sub> = 17.9 to 30V, I <sub>OUT</sub> = 500mA	-	-	150	mV	
Load regulation	$\Delta V_{RLOAD}$	I <sub>OUT</sub> = 5mA to 1.5A	-	-	225	mV	
Quiescent current	Ι <sub>Q</sub>	I <sub>OUT</sub> = 0mA	-	5.0	8.0	mA	
Quiescent current		Iout = 5mA to 1A	-	0.1	0.8		
change	Δlq	V <sub>IN</sub> = 17.9 to 30V, I <sub>OUT</sub> = 500mA	-	0.3	0.8	mA	
Output voltage	ΔV <sub>OUT</sub> / ΔΤ		-	1.2	-	mV/°C	
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)	1 -	-	80	-	ppm/°C	
Output noise voltage	V <sub>N</sub>	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / Vo	
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 18.5 to 28.5V, Іоит = 500mA	-	65	-	dB	
Dropout voltage <sup>(9)</sup>	VD	Iout = 1A	-	2.0	-	V	
Output resistance	Rout	f = 1kHz	-	18	-	mΩ	
Short circuit current	lsc	V <sub>IN</sub> = 35V		10	-	mA	
Peak current	Ірк	V <sub>IN</sub> = 21V	-	2.5	-	Α	

#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8)  $\pm 2\%$  for conventional device,  $\pm 1\%$  can be customized.

### 7.5 Electrical Characteristics (continued)

7818 ( $V_{IN}$  = 27V,  $I_{OUT}$  = 500mA,  $C_{IN}$  = 0.33 $\mu$ F,  $C_{OUT}$  = 0.1 $\mu$ F,  $T_J$  = 25°C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT	
		±2% grade <sup>(8)</sup>	17.64	18.00	18.36		
Output voltage	Vout	±1% grade <sup>(8)</sup>	17.82	10.00	18.18	v	
Output voltage	VOUT	$I_{OUT} = 5mA \text{ to } 1A, V_{IN} = 21 \text{ to } 33V,$ $T_J = -40 \text{ to } 125^{\circ}C$	17.28	18.00	18.72	v	
Line regulation	$\Delta V_{RLINE}$	V <sub>IN</sub> = 21 to 33V, I <sub>OUT</sub> = 500mA	-	-	180	mV	
Load regulation	$\Delta V_{RLOAD}$	I <sub>OUT</sub> = 5mA to 1.5A	-	-	270	mV	
Quiescent current	Ι <sub>Q</sub>	I <sub>OUT</sub> = 0mA	-	5.0	8.0	mA	
Quiescent current		Iout = 5mA to 1A	-	0.1	0.8	mA	
change	Δlq	V <sub>IN</sub> = 21 to 33V, I <sub>OUT</sub> = 500mA	-	0.3	0.8	ША	
Output voltage	ΔV <sub>OUT</sub> / ΔT		-	1.44	-	mV/°C	
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)	1 -	-	80	-	ppm/°C	
Output noise voltage	V <sub>N</sub>	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / Vo	
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 22 to 32V, Іоит = 500mA	-	65	-	dB	
Dropout voltage <sup>(9)</sup>	VD	I <sub>OUT</sub> = 1A	-	2.0	-	V	
Output resistance	Rout	f = 1kHz	-	10	-	mΩ	
Short circuit current	Isc	V <sub>IN</sub> = 35V		200	-	mA	
Peak current	Ірк	-	-	2.5	-	А	

#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8)  $\pm 2\%$  for conventional device,  $\pm 1\%$  can be customized.

## 7.5 Electrical Characteristics (continued)

7824	$(V_{IN} = 33V, I_{OUT} = 500mA,$	$C_{IN} = 0.33 \mu F, C_{OUT} = 0.1 \mu F, T$	Γ <sub>J</sub> = 25°C, unless otherwise specified)
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CHARACTERISTIC	SYMBOL	TEST CONDITIONS <sup>(7)</sup>	MIN.	TYP.	MAX.	UNIT	
		±2% grade <sup>(8)</sup>	23.52	24.00	24.48		
Output wells as		±1% grade <sup>(8)</sup>	23.76	24.00	24.24		
Output voltage	Vout	$I_{OUT} = 5$ mA to 1A, $V_{IN} = 27.3$ V to 38V, $T_J = -40$ to 125°C	23.04	24.00	24.96	V	
Line regulation	$\Delta V_{RLINE}$	$V_{IN}$ = 27V to 38V, $I_{OUT}$ = 500mA	-	-	240	mV	
Load regulation	$\Delta V_{RLOAD}$	I <sub>OUT</sub> = 5mA to 1.5A	-	-	360	mV	
Quiescent current	lα	Iout = 0mA	-	5.0	8.0	mA	
Quiescent current		I <sub>OUT</sub> = 5mA to 1A	-	0.1	0.8		
change	Δlq	V <sub>IN</sub> = 27 to 38V, I <sub>OUT</sub> = 500mA	-	0.3	0.8	mA	
Output voltage	ΔV <sub>OUT</sub> / ΔT		-	1.92	-	mV/°C	
temperature coefficient	ΔV <sub>OUT</sub> / (V <sub>OUT</sub> × ΔT)		-	80	-	ppm/°C	
Output noise voltage	V <sub>N</sub>	f = 10 to 100k Hz, T <sub>A</sub> = 25°C	-	10	-	μV / Vo	
Ripple rejection	RR	f = 120Hz, V <sub>IN</sub> = 28V to 38V, I <sub>OUT</sub> = 500mA	-	65	-	dB	
Dropout voltage <sup>(9)</sup>	VD	I <sub>OUT</sub> = 1A	-	2.0	-	V	
Output resistance	Rout	f = 1kHz	-	1.4	-	mΩ	
Short circuit current	lsc	V <sub>IN</sub> = 35V		200	-	mA	
Peak current	Ірк	-	-	2.5	-	А	

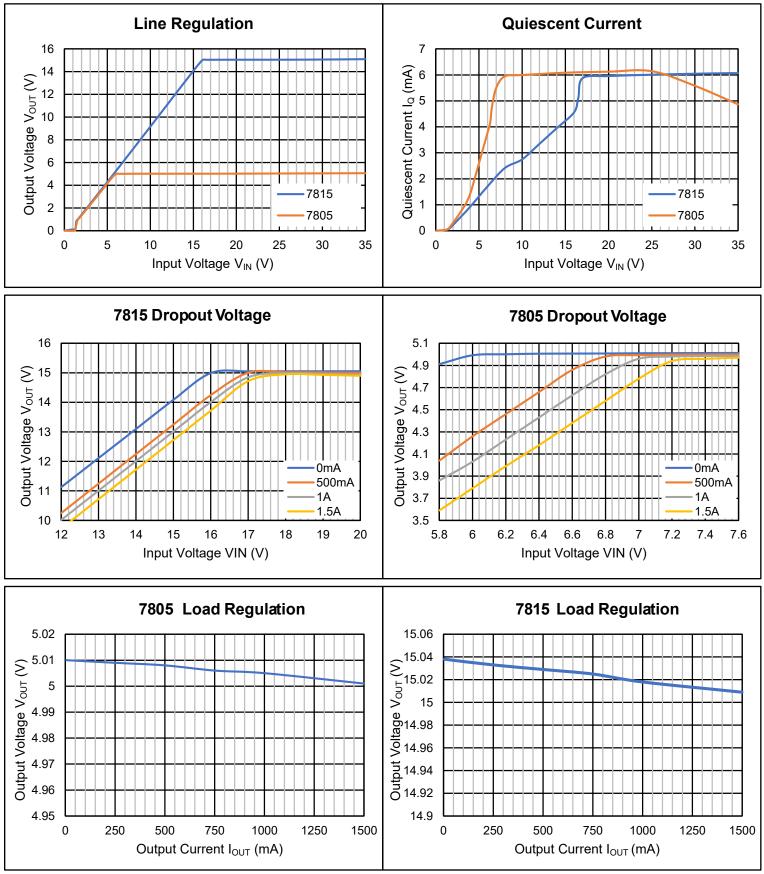
#### Note:

(7) Pulse test technology is used to make  $T_J$  as close to  $T_A$  as possible. Thermal effects must be considered separately.

(8)  $\pm 2\%$  for conventional device,  $\pm 1\%$  can be customized.

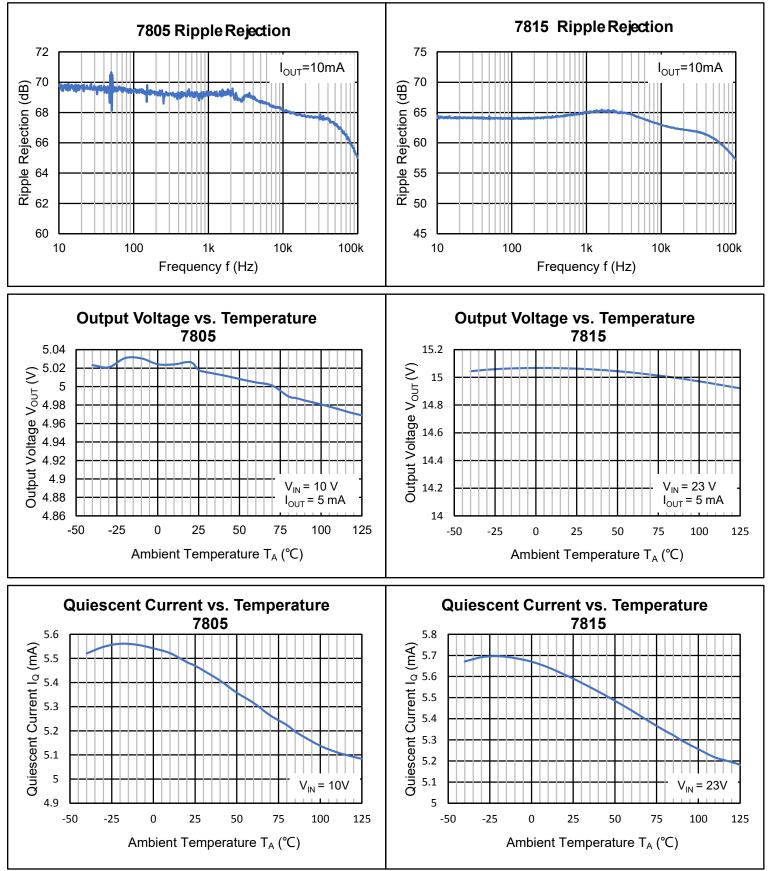
### 7.6 Typical Characteristics

NSD78XX Series (V<sub>IN</sub> = 10V for 7805 , V<sub>IN</sub> = 23V for 7815 , I<sub>OUT</sub> = 500mA, C<sub>IN</sub> = 0.33 $\mu$ F, C<sub>OUT</sub> = 0.1 $\mu$ F, TA = 25°C, unless otherwise specified)



## 7.6 Typical Characteristics (continued)

NSD78XX Series (V<sub>IN</sub> = 10V for 7805 , V<sub>IN</sub> = 23V for 7815 , I<sub>OUT</sub> = 500mA, C<sub>IN</sub> = 0.33µF, C<sub>OUT</sub> = 0.1µF, TA = 25°C, unless otherwise specified)



### 7.6 Typical Characteristics (continued)

NSD78XX Series (V<sub>IN</sub> = 10V for 7805 , V<sub>IN</sub> = 23V for 7815 , I<sub>OUT</sub> = 500mA, C<sub>IN</sub> =  $0.33\mu$ F, C<sub>OUT</sub> =  $0.1\mu$ F, TA = 25°C, unless otherwise specified)

#### Load Transient

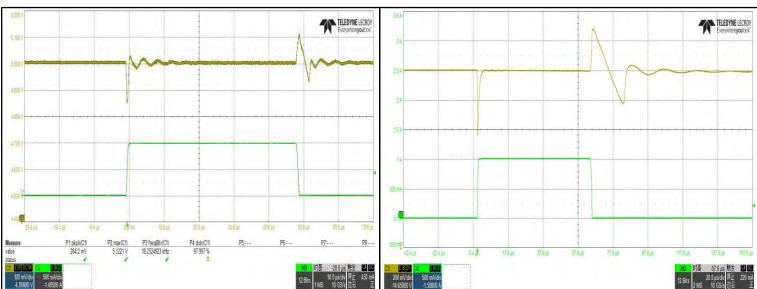
#### 7805 , $V_{IN}$ = 10V, CH<sub>1</sub>: $V_{OUT}$ , CH<sub>4</sub>: $I_{OUT}$

#### Load Transient

7815 ,  $V_{IN}$  = 23V, CH<sub>1</sub>:  $V_{OUT}$ , CH<sub>4</sub>:  $I_{OUT}$ 

I<sub>OUT</sub> = 10 to 1000mA

I<sub>OUT</sub> = 1.5 to 1000mA

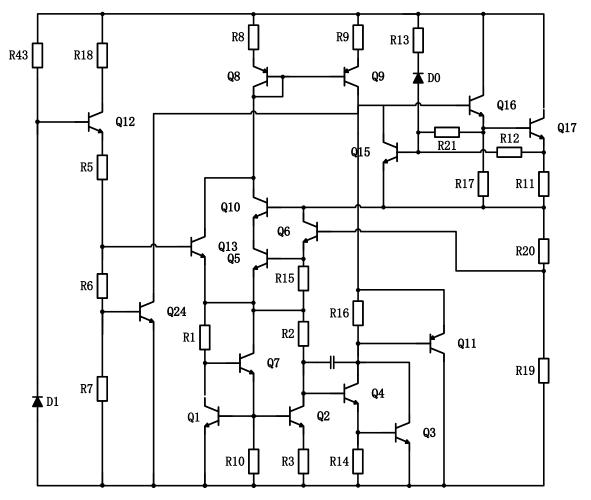


## 8 Detailed Description

### 8.1 Description

The NSD78XX series is a group of fixed output positive voltage regulators . Itintegrates built-in current limit , shortcircuit protection, thermal overload protection and safe operating area protection of output transistor, which makes it relatively difficult to be damaged . By setting there sistance value of peripheral resistance, the NSD78XX series can also be used as adjustable voltage output regulator.

### 8.2 Representative Schematic Diagram



#### 8.3 Feature Description

#### Input Voltage

When the input voltage is lower than the rated range of the data sheet, the device will lose the regulation function of stabilizing the output voltage, that is, it is unable to maintain the output voltage within the rated range. When the input voltage is higher than the rated range of the data sheet, the device may cause irreversible damage or failure due to exceeding the maximum rated range of electrical stress.

#### **Built-in Current Limit & Short Circuit Protection**

The NSD78XX series has built-in current limit and short circuit protection. When the output current of the device is too high, the output of the device will be shut down. When the output of the device is short circuited to ground, the output of the device will also be shut down and the output current will be maintained within a certain range. The typical current limits for the NSD78XX series is 2.2A.

### 8 Detailed Description

### 8.3 Feature Description (continued)

#### **Thermal Shutdown Protection**

The NSD78XX series has thermal shutdown protection. When the junction temperature exceeds the rated temperature range for normal operation in the data sheet, the device will enter the thermal shutdown state. At this time, the output voltage of the device will be reduced to prevent catastrophic damage to the chip due to accidental heat. When the junction temperature decreases and no longer remains too high, the device will release the thermal shutdown and output normally. To ensure reliable operation, please limit the junction temperature to the specified range of recommended operating conditions in the data sheet. Applications that exceed the recommended temperature range may cause the device to exceed its operating specifications.

Although the internal protection circuitry of the device is designed to protect against thermal overall conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above the maximum recommended junction temperature reduces long-term reliability.

#### **Output Current**

Due to the internal integration of thermal shutdown protection, in the case of large output current, the device may enter the thermal shutdown state because the junction temperature is higher than the rated value in the data sheet. Therefore, the appropriate package should be selected for circuit design according to the heat dissipation power consumption of the package and the effective connection thermal resistance with the environment, so as to make the device emit more heat energy, so as to ensure the maximum load current capacity of the device. If the circuit design is appropriate and the device has good heat dissipation conditions, the NSD78XX series can output a current of up to 1.5A.

### 9 Application and Implementation

#### 9.1 Risk Alert and Precautions

The NSD78XXseries is designed with thermal protection, output short circuit protection and output transistor SOA protection. However, like any IC regulator, precautions are necessary to reduce the possibility of accidental damage to the regulator. The following describes the possible causes of unit damage or failure:

#### Electrostatic Discharge (ESD) and Instantaneous Electrical Surge

Electrostatic discharge (ESD) is a common near-field hazard source. It comes from many sources, such as human body, mechanical equipment and electronic components themselves. ESD can cause phenomena such as high voltage and instantaneous high current in a very short time, resulting in damage or failure of the device due to electric shock.

In some applications, a short duration but high energy spike may occur in the circuit, including peak voltage and surge current. They may cause unstable operation of the regulator, accelerated aging and potential hazards, and even damage or malfunction of the regulator. These peaks are usually more likely to occur in hot-plug, switch inductance, heavy-load, and other types of circuits.

#### Precautions for ESD and Electrical Surge

In the practical application of the circuit, adopting the following suggestions can reduce the possibility of device failure due to the above reasons to a certain extent.

#### Using TVS:

Place a TVS between the IN and GND of the voltage regulator to absorb the peak voltage that may be generated due to ESD or other reasons. As shown in Figure 9-4;

#### Using Input Resistor:

Place a resistor with appropriate resistance in series before the IN of the voltage regulator, which can help the voltage regulator share part of the energy in case of surge. The resistance value of the resistance should not be too large. The specific resistance value depends on the application of the circuit. Generally, the resistance value of this resistance does not exceed  $20\Omega$ . As shown in Figure 9-5;

#### Using Electrolytic Capacitor:

For the application circuit using the low ESR multilayer ceramic capacitor (MLCC) type input capacitor, the LC resonant voltage spike caused by hot plugging or power transmission line inductance can be suppressed by using RC suppression circuit for parallel connection of the input capacitor. A very simple method is to parallel a suitable electrolytic capacitor to the input capacitor. As shown in Figure 9-6. For most  $100\mu$ F/25V electrolytic capacitor has an ESR of about 0.2 $\Omega$  at 100kHz. This can completely suppress the overshoot phenomenon of the input and minimize the possibility of IC damage due to input voltage spikes.

Figure 9-1 and Figure 9-2 show the impact of not using electrolytic capacitor [Test circuit is shown in Figure 9-3] and using  $100\mu$ F/25V electrolytic capacitor parallel to the input capacitor [Test circuit is shown in Figure 9-6] on suppressing surge voltage. As shown in Figure 9-1., when the input is powered on from 0 to 10V, a peak voltage of up to 15V (shown in the RED part) is generated in front of the input terminal of the device. When the electrolytic capacitor is used, as shown in Figure 9-2., the peak voltage generated by power on is effectively suppressed (shown in the GREEN part).

### 9 Application and Implementation

#### 9.1 Risk Alert and Precautions (continued)

Test Condition: 7805,  $C_{IN} = 10\mu F$  (MLCC),  $C_{OUT} = 100\mu F$ ,  $V_{IN} = 0 \sim 10V$ ,  $I_{OUT} = 100mA$ ,  $CH_1$ :  $V_{IN}$ ,  $CH_2$ :  $V_{OUT}$ .

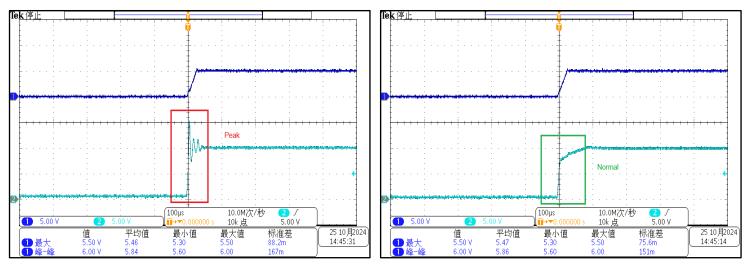


Figure 9-1. Test with the conventional circuit

Figure 9-2. Test with the circuit that a 100µF/25V electrolytic capacitor parallel to the C<sub>IN</sub> [Test Circuit is shown in Figure 9-6]

For the NSD78XX series, it is recommended that the input peak voltage should not exceed 36V. When the input voltage of the operating circuit may not meet the application conditions described above, it is recommended to adopt the circuit layout shown in Figure 9-5 in the circuit design.

#### Large Output Capacitance

The NSD78XX series can obtain better transient response with the help of output capacitance. However if the output capacitor is relatively large, the surge current generated by the charging of the output capacitor will also be large at the moment of power on of the regulator, and the large surge current passing through the regulator may damage the internal circuit. When the output capacitance is large, adopting the circuit design shown in Figure 9-5 will reduce the possibility of damage to the device due to large surge current to a certain extent. It is recommended that the selection of output capacitor should not exceed 20µF. If the selection of output capacitor exceeds 20µF, it is recommended to adopt the circuit design in Figure 9-5 to reduce the possibility of accidental failure of the device due to large surge current during power on.

### 9.2 Typical Application Circuits

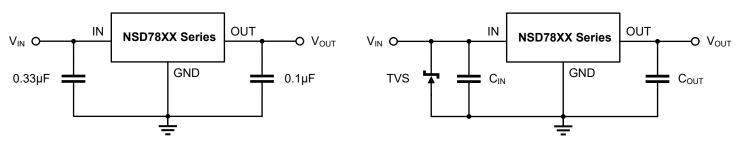


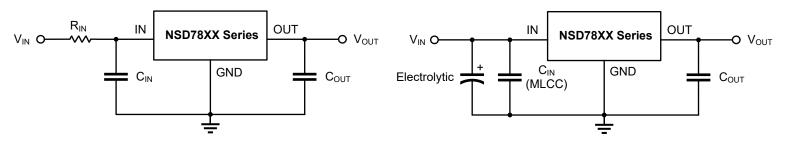


Figure 9-4. TVS is used at IN

<sup>[</sup>Test Circuit is shown in Figure 9-3]

### 9 Application and Implementation

### 9.2 Typical Application Circuits (continued)



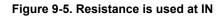


Figure 9-6. Electrolytic capacitor is used at IN

### 9.3 Bypass Capacitance Selection

A capacitance between IN and GND ( $C_{IN}$ ) is required if the regulator is located far from the power supply filter. It is recommended to use a  $0.33\mu$ F capacitor for  $C_{IN}$ , and the  $C_{IN}$  should be placed as close to the device IN pin and GND pin as possible.

It is recommended to use a  $0.1\mu$ F capacitor between OUT and GND ( $C_{OUT}$ ), and the  $C_{OUT}$  should be placed as close as possible between OUT and GND. The output capacitance can limit the high-frequency noise and help the device obtain the best stability and transient response.

The tolerance and temperature coefficient of the  $C_{IN}$  and  $C_{OUT}$  must be considered to ensure that the capacitor can work normally within the rated working ambient temperature and rated working conditions of the device.

It is recommended that the  $C_{OUT}$  should not exceed 20µF. When the  $C_{OUT}$  exceeds 20µF, it is recommended to use the circuit layout shown in Figure 9-2. See *Large Output Capacitance* for more details.

### 9.4 Design Requirements and Procedure

The NSD78XX series is mainly used to provide fixed output voltage regulation, the output voltage is selected based on the device variant, which is available in 5.0V, 6.0V, 8.0V, 9.0V, 12V, 15V and 18V regulator options, and it requires a very small number of device components. If the regulator is far from the power filter, the input capacitor  $C_{IN}$  is required. The bypass capacitor  $C_{OUT}$  is used at the output to obtain the best stability and transient response. These capacitors must be as close to the regulator as possible.

### 9.5 Power Supply Recommendation

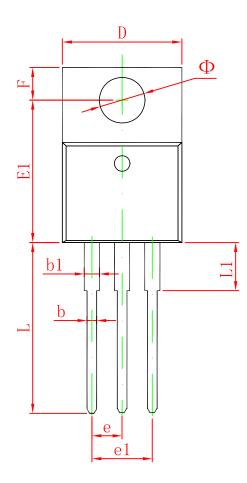
The linear regulator input supply must be well regulated and kept at a voltage level to not exceed the maximum input to output voltage differential allowed by the device. The minimum dropout voltage ( $V_{DO}$ ) must be meet with extra headroom when possible to keep the output well regulated.

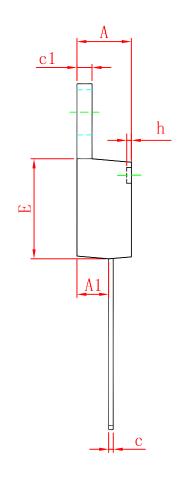
For the best overall performance, some layout guidelines may be disregarded. Place all circuit components on the same side of the circuit board and as near as practical to the respective linear regulator pins. Traces must be kept short and wide to reduce the amount of parasitic elements in the system. The actual width and thickness of traces depends on the current carrying capability and heat dissipation required by the end system.

## 10 Mechanical Information

### 10.1 TO-220-3L Mechanical Information

TO-220-3L Outline Dimensions



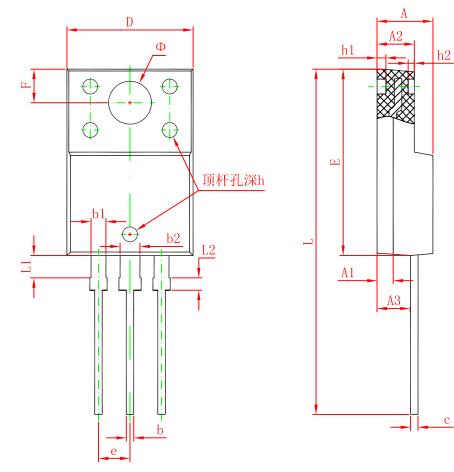


Symbol	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
A	4.470	4.670	0.176	0.184
A1	2.520	2.820	0.099	0.111
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
С	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
E1	12.060	12.460	0.475	0.491
е	2.540	) TYP	0.100	) TYP
e1	4.980	5.180	0.196	0.204
F	2.590	2.890	0.102	0.114
h	0.000	0.300	0.000	0.012
L	13.400	13.800	0.528	0.543
L1	3.560	3.960	0.140	0.156
Φ	3.735	3.935	0.147	0.155

## 10 Mechanical Information

## 10.2 TO-220F Mechanical Information

### **TO-220F Outline Dimensions**

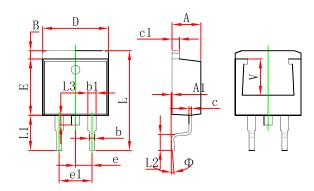


Symbol	Dimensions	In Millimeters	Dimension	s In Inches		
Symbol	Min.	Max.	Min.	Max.		
A	4.300	4.700	0.169	0.185		
A1	1.300 REF.		0.051	REF.		
A2	2.800	3.200	0.110	0.126		
A3	2.500	2.900	0.098	0.114		
b	0.500	0.750	0.020	0.030		
b1	1.100	1.350	0.043	0.053		
b2	1.500	1.750	0.059	0.069		
С	0.500	0.750	0.020	0.030		
D	9.960	10.360	0.392	0.408		
E	14.800	15.200	0.583	0.598		
е	2.540	TYP.	0.100	) TYP.		
F	2.700	REF.	0.106	REF.		
Φ	3.500	REF.	0.138	REF.		
h	0.000	0.300	0.000	0.012		
h1	0.800	REF.	0.031	0.031 REF.		
h2	0.500 REF.		0.020	0.020 REF.		
L	28.000	28.400	1.102	1.118		
L1	1.700	1.900	0.067	0.075		
L2	0.900	1.100	0.035	0.043		

### **10** Mechanical Information

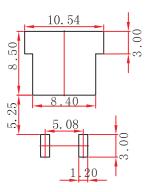
10.3 TO-263-2L Mechanical Information

**TO-263-2L Outline Dimensions** 



0	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min.	Max.	Min.	Max.
А	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
В	1.120	1.420	0.044	0.056
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
с	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
е	2.540	TYP.	0.100	TYP.
e1	4.980	5.180	0.196	0.204
L	14.940	15.500	0.588	0.610
L1	4.950	5.450	0.195	0.215
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
Φ	0°	8°	0°	8°
V	5.600	REF.	0.220	REF.

#### TO-263-2L Suggest Pad Layout



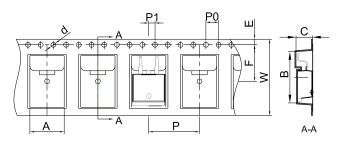
#### NOTE:

- 1. Controlling dimension: in millimeters.
- 2. General tolerance: ±0.05mm.
- 3. The pad layout is for reference purposes only.

### 11 Packaging Information

#### 11.2 TO-263-2L Tape and Reel Information

#### TO-263-2L Embossed Carrier Tape

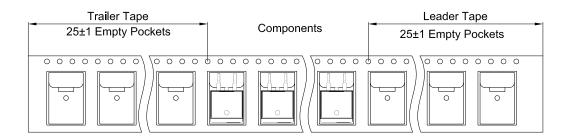


#### Packaging Description:

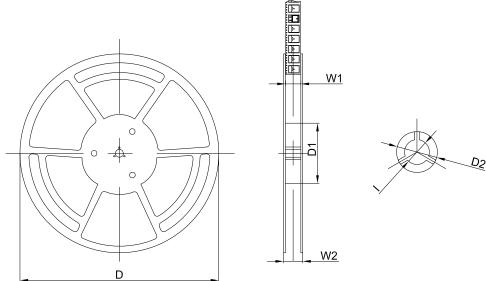
TO-263-2L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 800 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

	Dimensions are in millimeter							
Pkg type	Pkg type A B C d E F P0 P P1 W							
TO-263-2L	TO-263-2L 10.80 16.13 5.21 Ø1.55 1.75 11.50 4.00 16.00 2.00 24.00							

#### TO-263-2L Tape Leader and Trailer



TO-263-2L Reel



Dimensions are in millimeter									
Reel Option	Reel Option D D1 D2 W1 W2 I								
13"Dia	13"Dia Ø330.00 100.00 Ø21.00 24.4 30.4 Ø13.00								

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
800 pcs	13 inch	800 pcs	340×336×36	8,000 pcs	400×353×365	

### 12 Notes and Revision History

#### 12.1 Associated Product Family and Others

To view other products of the same type or IC products of other types, please click the official web site of NSDwww.nsd.hqew.com for more details.

#### 12.2 Notes

#### **Electrostatic Discharge Caution**



This IC may be damaged by ESD. Relevant personnel shall comply with correct installation and use specifications to avoid ESD damage to the IC. If appropriate measures are not taken to prevent ESD damage, the hazards caused by ESD include but are not limited to degradation of integrated circuit performance or complete damage of integrated circuit. For some precision integrated circuits, a very small parameter change may cause the whole device to be inconsistent with its published specifications.